Sheet 1 of 1

FORM PTO-1449 (REV.7-80)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE			ATTY. DOCKET NO. 501265.01	AI AN	APPLICATION NO. 10 74873		
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A	ΑP	Favrat, Pierre et al., "A High-Efficiency CMOS Voltage Doubler", IEEE Journal of Solid-State Circuits, Vol. 33, No. 3, March 1998, pp. 410-416.							
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